

PBSS4032PZ

30 V, 4.4 A PNP low V_{CEsat} (BISS) transistor

Rev. 01 — 31 March 2010

Product data sheet

1. Product profile

1.1 General description

PNP low V_{CEsat} Breakthrough In Small Signal (BISS) transistor in a medium power SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4032NZ.

1.2 Features and benefits

- Low collector-emitter saturation voltage V_{CEsat}
- Optimized switching time
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- High energy efficiency due to less heat generation
- AEC-Q101 qualified
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors

1.3 Applications

- DC-to-DC conversion
- Battery-driven devices
- Power management
- Charging circuits

1.4 Quick reference data

Table 1. Quick reference data

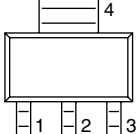
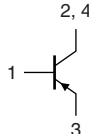
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------|--|----------------------------------|-----------------------|-----|------|------------|
| V_{CEO} | collector-emitter voltage | open base | - | - | -30 | V |
| I_C | collector current | | - | - | -4.4 | A |
| I_{CM} | peak collector current | single pulse; $t_p \leq 1$ ms | - | - | -10 | A |
| R_{CEsat} | collector-emitter saturation resistance | $I_C = -4$ A; $I_B = -400$ mA | [1] - | 58 | 86 | m Ω |

[1] Pulse test: $t_p \leq 300$ μ s; $\delta \leq 0.02$.



2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline | Graphic symbol |
|-----|-------------|---|---|
| 1 | base |  |  |
| 2 | collector | | |
| 3 | emitter | | |
| 4 | collector | | |

sym028

3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|---|---------|
| | Name | Description | Version |
| PBSS4032PZ | SC-73 | plastic surface-mounted package with increased heat sink; 4 leads | SOT223 |

4. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PBSS4032PZ | PB4032PZ |

5. Limiting values

Table 5. Limiting values

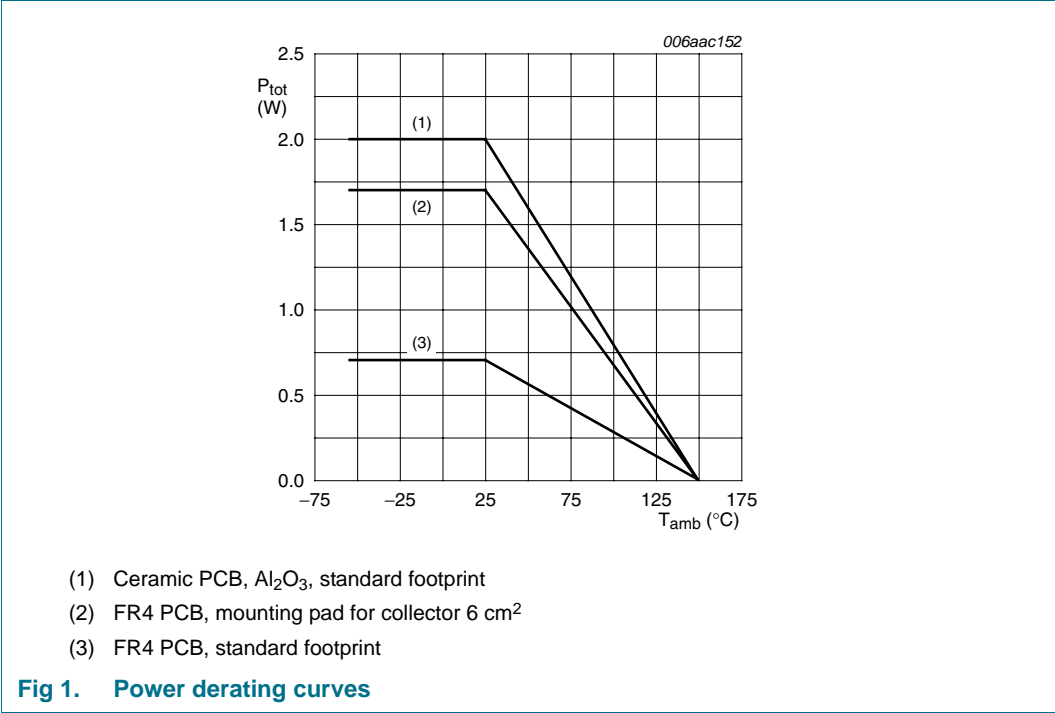
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|---------------------------|----------------------------------|-----|------|------|
| V_{CBO} | collector-base voltage | open emitter | - | -30 | V |
| V_{CEO} | collector-emitter voltage | open base | - | -30 | V |
| V_{EBO} | emitter-base voltage | open collector | - | -5 | V |
| I_C | collector current | | - | -4.4 | A |
| I_{CM} | peak collector current | single pulse; $t_p \leq 1$ ms | - | -10 | A |
| I_B | base current | | - | -1 | A |

Table 5. Limiting values ...continued
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|--------------------------|-------|------|------|
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] - | 700 | mW |
| | | | [2] - | 1700 | mW |
| | | | [3] - | 2000 | mW |
| T _j | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -55 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².
- [3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.



6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|--|-------------|-------|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1] - | - | 180 | K/W |
| | | | [2] - | - | 75 | K/W |
| | | | [3] - | - | 65 | K/W |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | | - | - | 15 | K/W |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².
- [3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

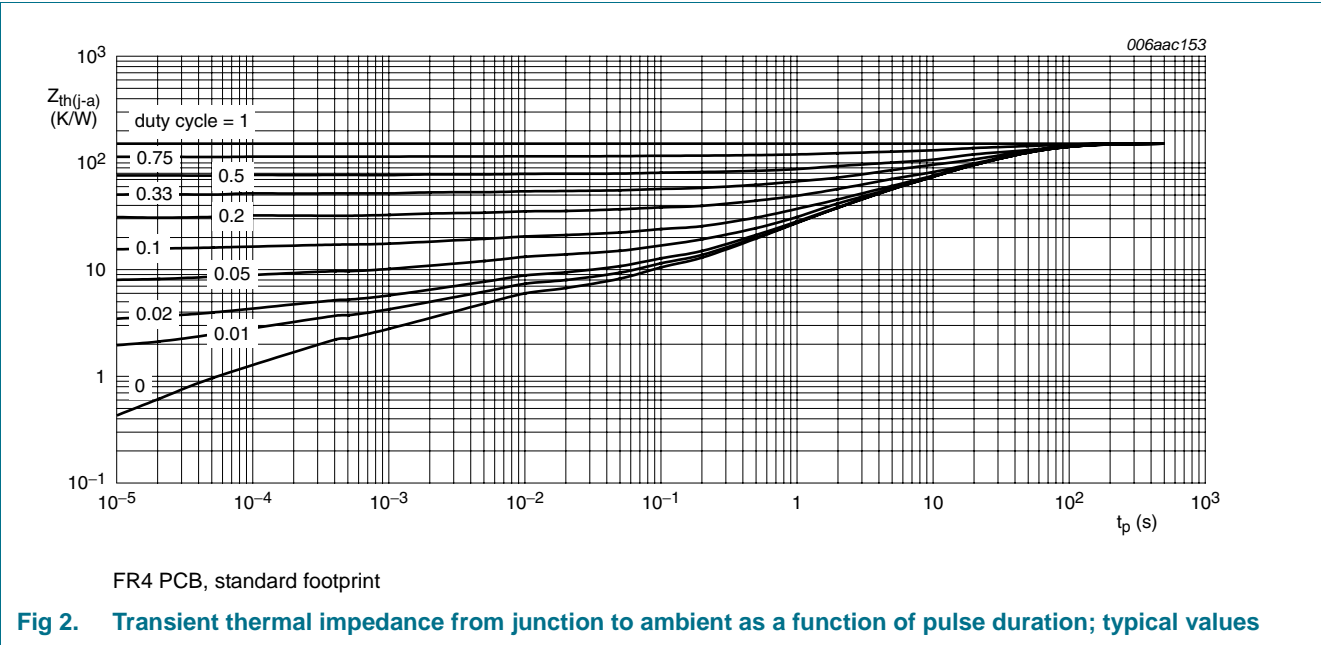
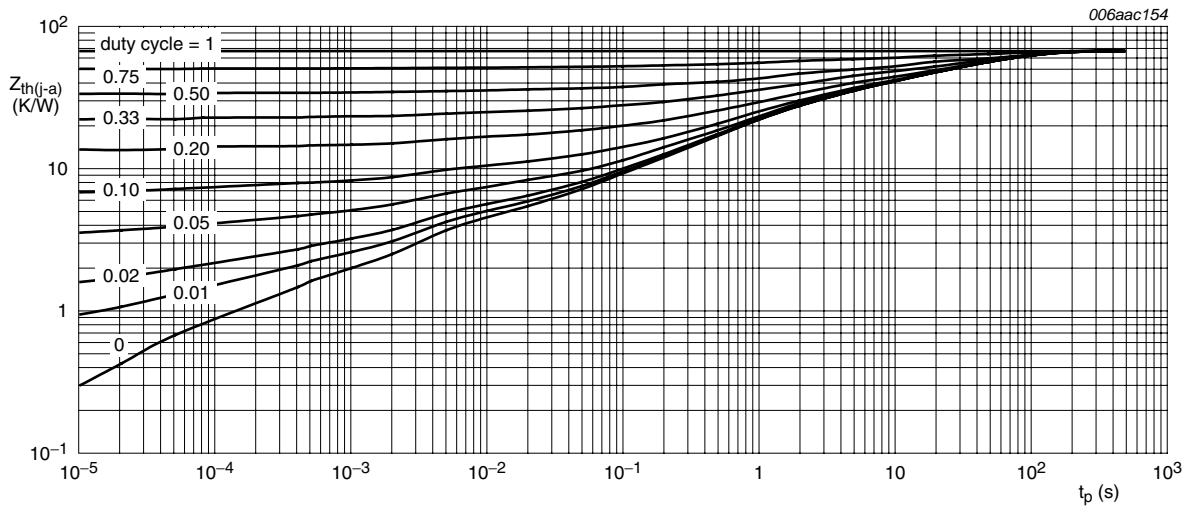
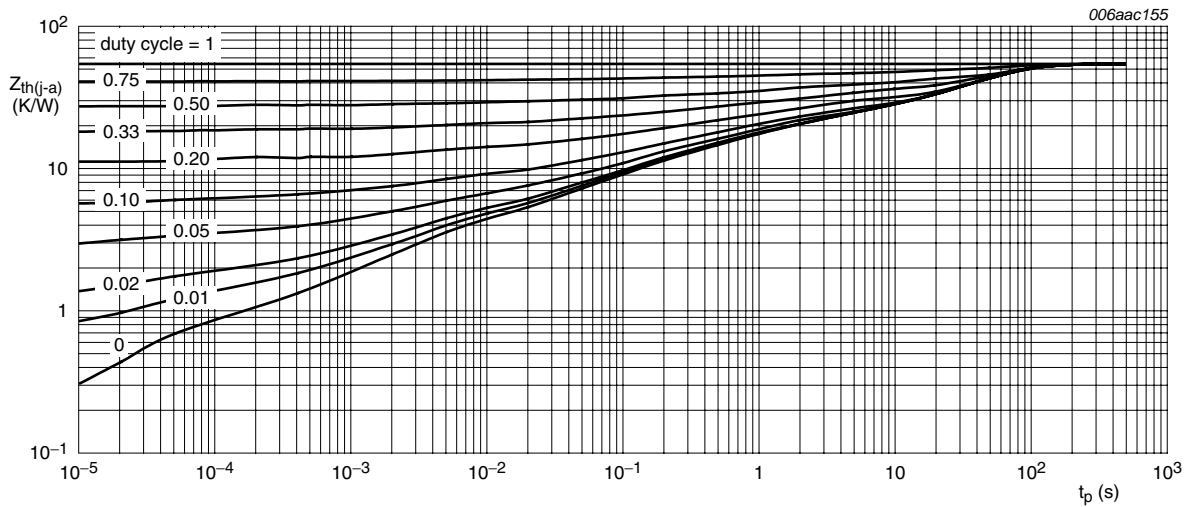


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for collector 6 cm²

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB, Al₂O₃, standard footprint

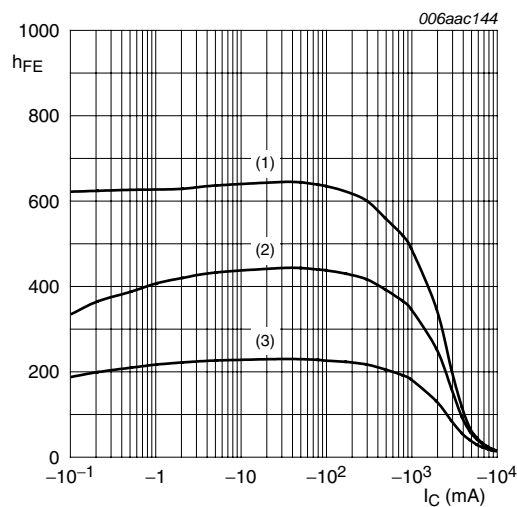
Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

7. Characteristics

Table 7. Characteristics
 $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

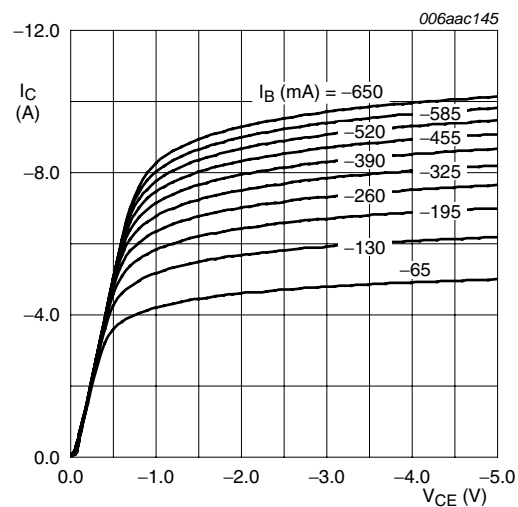
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|--------------------|---|--|------|------|-------|-------|----|
| I _{CBO} | collector-base cut-off current | V _{CB} = −30 V; I _E = 0 A | - | - | −100 | nA | |
| | | V _{CB} = −30 V; I _E = 0 A; T _j = 150 °C | - | - | −55 | μA | |
| I _{CES} | collector-emitter cut-off current | V _{CE} = −24 V; V _{BE} = 0 V | - | - | −100 | nA | |
| I _{EBO} | emitter-base cut-off current | V _{EB} = −5 V; I _C = 0 A | - | - | −100 | nA | |
| h _{FE} | DC current gain | [1] | | | | | |
| | | V _{CE} = −2 V; I _C = −500 mA | 200 | 350 | - | | |
| | | V _{CE} = −2 V; I _C = −1 A | 200 | 320 | - | | |
| | | V _{CE} = −2 V; I _C = −2 A | 150 | 240 | - | | |
| | | V _{CE} = −2 V; I _C = −4 A | 60 | 100 | - | | |
| V _{CEsat} | collector-emitter saturation voltage | [1] | | | | | |
| | | I _C = −1 A; I _B = −50 mA | - | −110 | −165 | mV | |
| | | I _C = −1 A; I _B = −10 mA | - | −160 | −240 | mV | |
| | | I _C = −2 A; I _B = −40 mA | - | −200 | −300 | mV | |
| | | I _C = −4 A; I _B = −400 mA | - | −230 | −345 | mV | |
| | I _C = −4 A; I _B = −200 mA | - | −270 | −400 | mV | | |
| R _{CEsat} | collector-emitter saturation resistance | I _C = −4 A; I _B = −400 mA | [1] | - | 58 | 86 | mΩ |
| V _{BEsat} | base-emitter saturation voltage | I _C = −1 A; I _B = −100 mA | [1] | - | −0.79 | −0.9 | V |
| | | I _C = −4 A; I _B = −400 mA | [1] | - | −0.99 | −1.05 | V |
| V _{BEon} | base-emitter turn-on voltage | V _{CE} = −2 V; I _C = −2 A | [1] | - | −0.81 | −0.9 | V |
| t _d | delay time | V _{CC} = −12.5 V; | - | 30 | - | ns | |
| t _r | rise time | I _C = −1 A; I _{Bon} = −0.05 A; | - | 60 | - | ns | |
| t _{on} | turn-on time | I _{Boff} = 0.05 A | - | 90 | - | ns | |
| t _s | storage time | | - | 140 | - | ns | |
| t _f | fall time | | - | 80 | - | ns | |
| t _{off} | turn-off time | | - | 220 | - | ns | |
| f _T | transition frequency | V _{CE} = −10 V; I _C = −100 mA; f = 100 MHz | - | 130 | - | MHz | |
| C _c | collector capacitance | V _{CB} = −10 V; I _E = i _e = 0 A; f = 1 MHz | - | 65 | - | pF | |

[1] Pulse test: $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$.



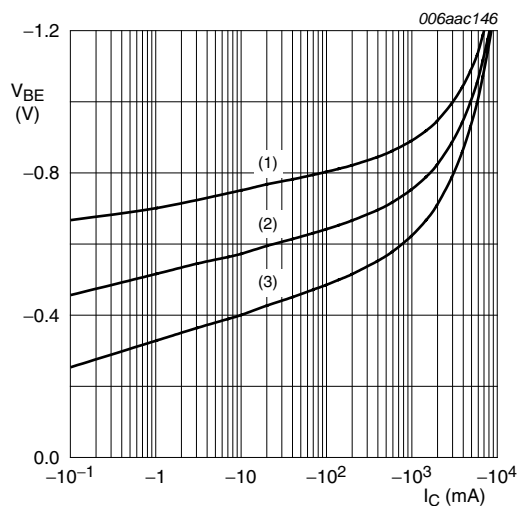
$V_{CE} = -2\text{ V}$
(1) $T_{amb} = 100\text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
(3) $T_{amb} = -55\text{ }^{\circ}\text{C}$

Fig 5. DC current gain as a function of collector current; typical values



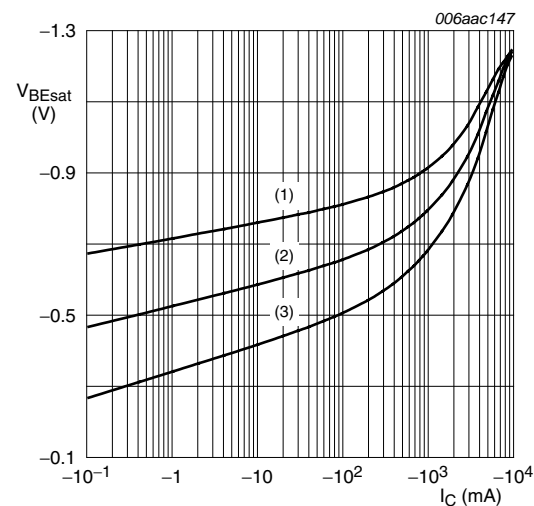
$T_{amb} = 25\text{ }^{\circ}\text{C}$

Fig 6. Collector current as a function of collector-emitter voltage; typical values



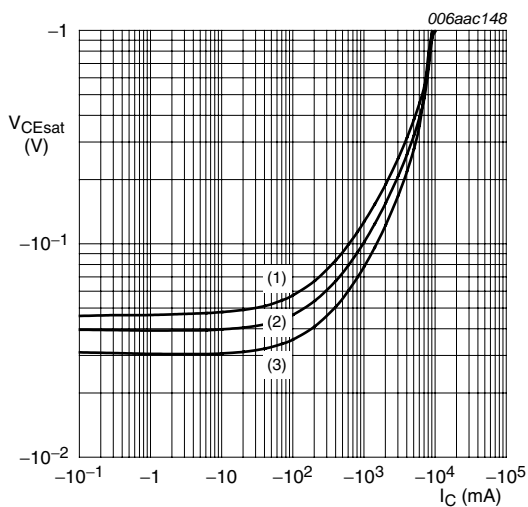
$V_{CE} = -2\text{ V}$
(1) $T_{amb} = -55\text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
(3) $T_{amb} = 100\text{ }^{\circ}\text{C}$

Fig 7. Base-emitter voltage as a function of collector current; typical values



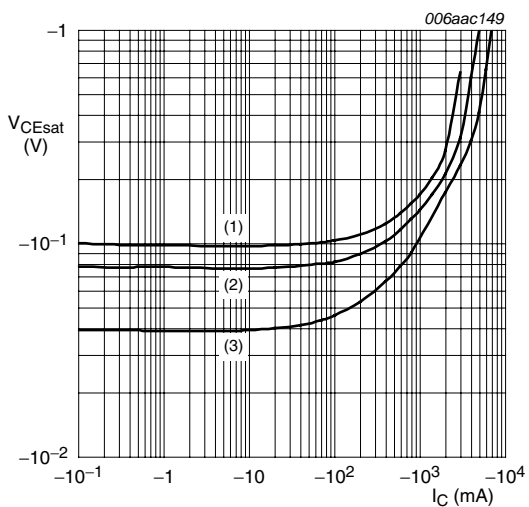
$I_C/I_B = 20$
(1) $T_{amb} = -55\text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
(3) $T_{amb} = 100\text{ }^{\circ}\text{C}$

Fig 8. Base-emitter saturation voltage as a function of collector current; typical values



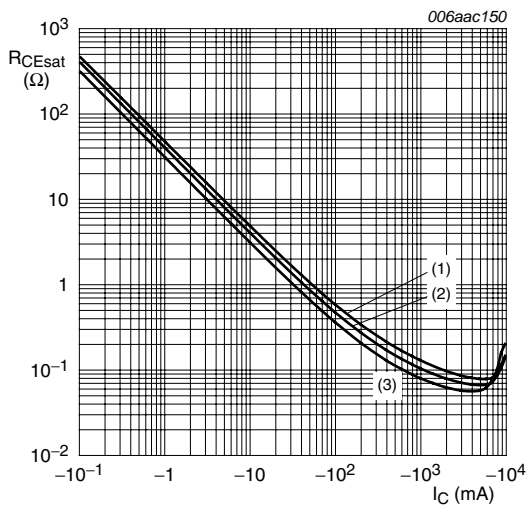
- $I_C/I_B = 20$
- (1) $T_{amb} = 100\text{ }^{\circ}\text{C}$
 - (2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
 - (3) $T_{amb} = -55\text{ }^{\circ}\text{C}$

Fig 9. Collector-emitter saturation voltage as a function of collector current; typical values



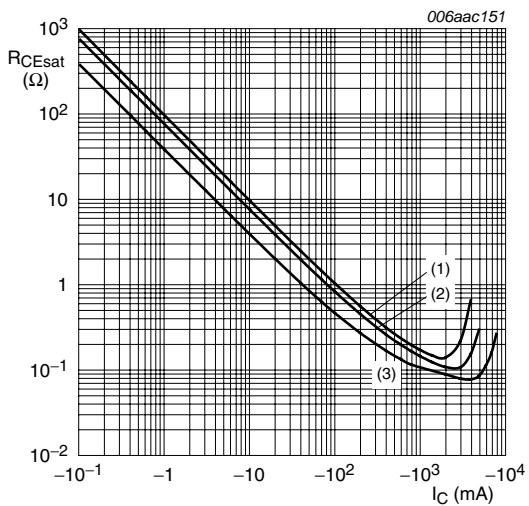
- $T_{amb} = 25\text{ }^{\circ}\text{C}$
- (1) $I_C/I_B = 100$
 - (2) $I_C/I_B = 50$
 - (3) $I_C/I_B = 10$

Fig 10. Collector-emitter saturation voltage as a function of collector current; typical values



- $I_C/I_B = 20$
- (1) $T_{amb} = 100\text{ }^{\circ}\text{C}$
 - (2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
 - (3) $T_{amb} = -55\text{ }^{\circ}\text{C}$

Fig 11. Collector-emitter saturation resistance as a function of collector current; typical values



- $T_{amb} = 25\text{ }^{\circ}\text{C}$
- (1) $I_C/I_B = 100$
 - (2) $I_C/I_B = 50$
 - (3) $I_C/I_B = 10$

Fig 12. Collector-emitter saturation resistance as a function of collector current; typical values

8. Test information

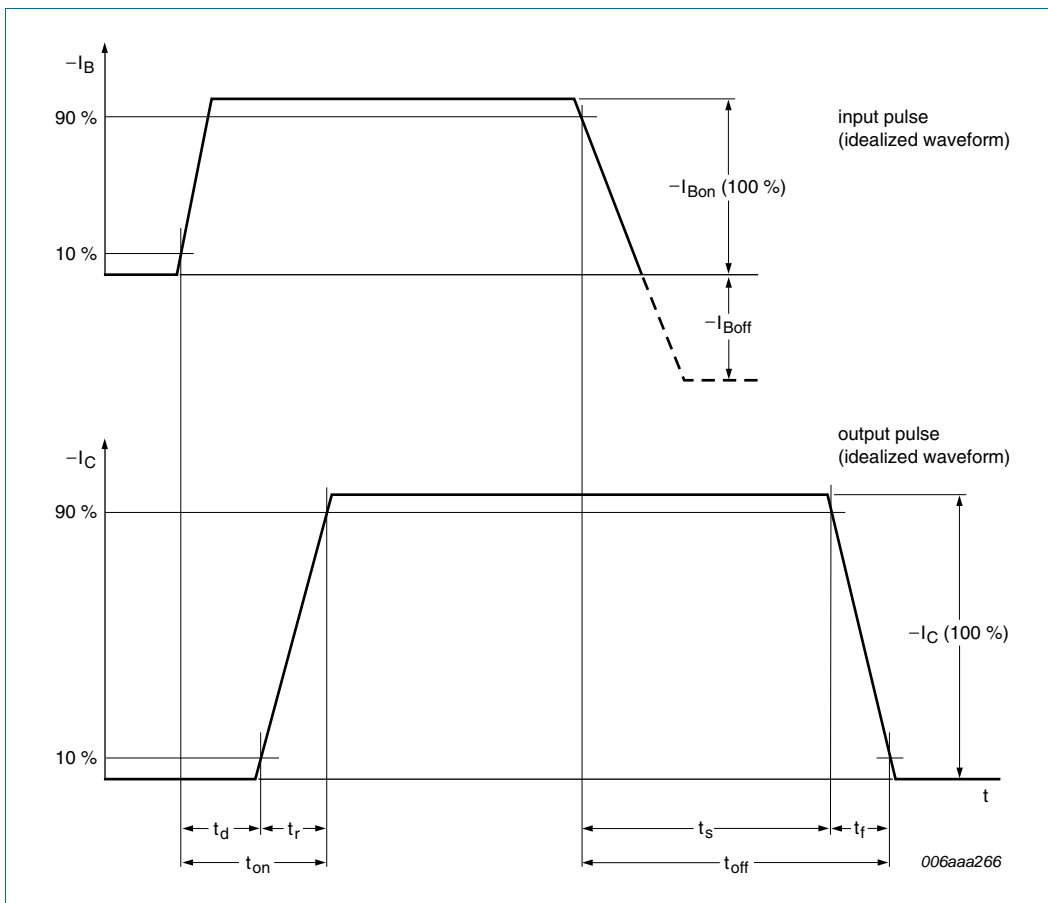


Fig 13. BISS transistor switching time definition

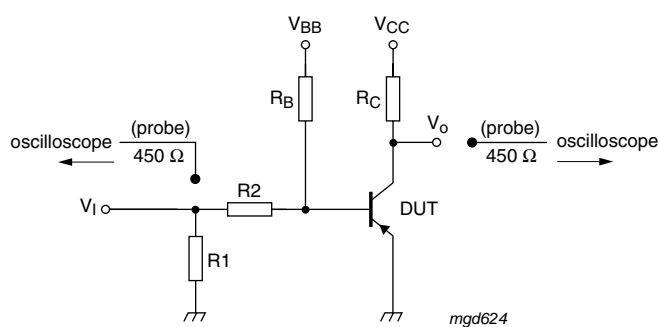
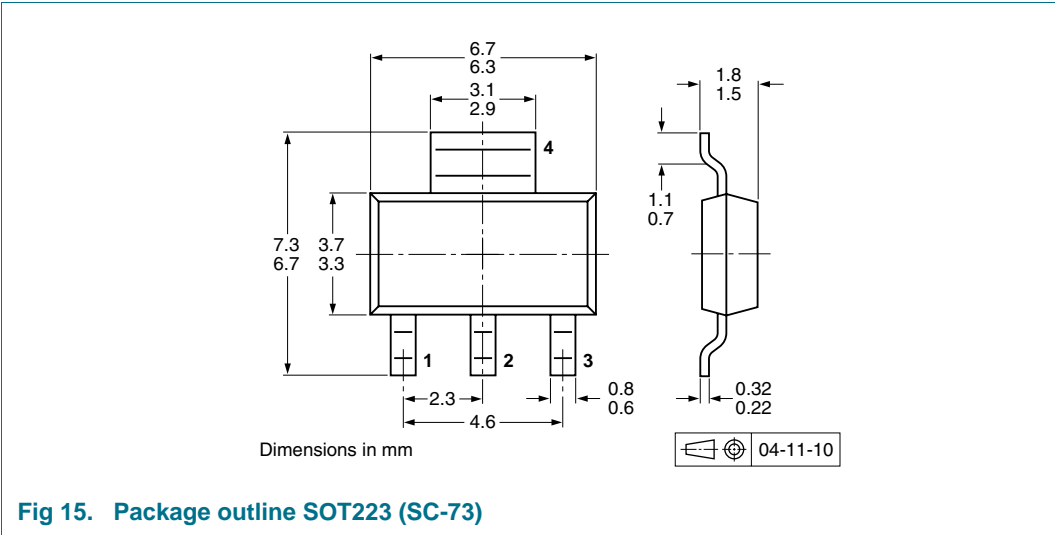


Fig 14. Test circuit for switching times

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

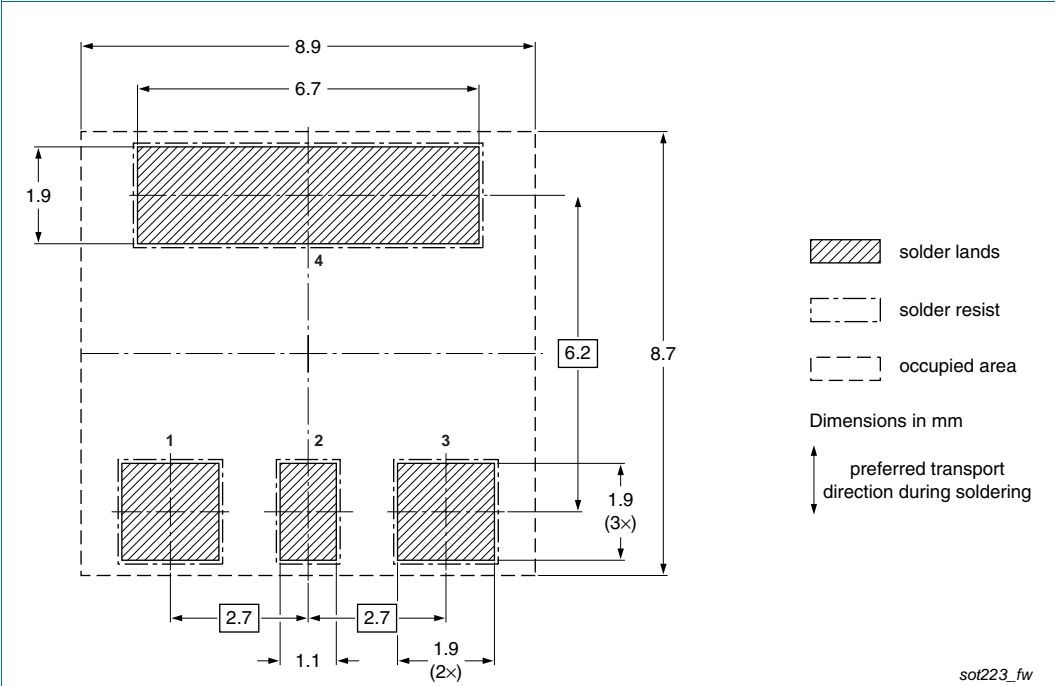
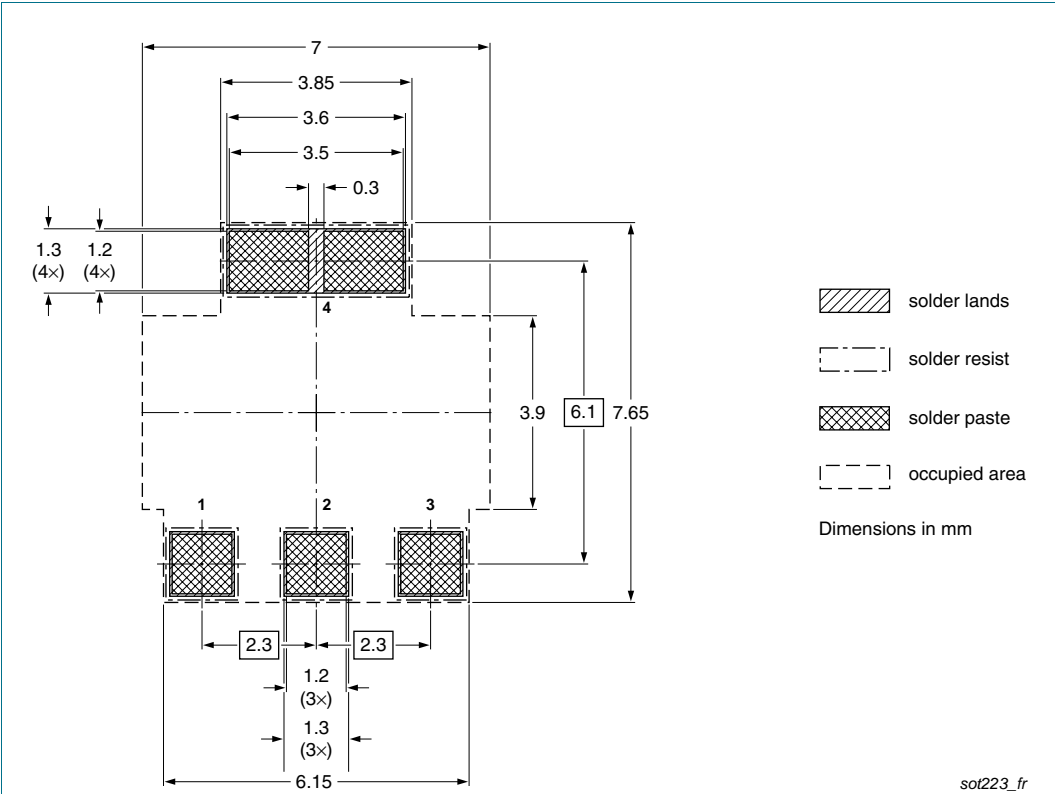
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

| Type number | Package | Description | Packing quantity | |
|-------------|---------|---------------------------------|------------------|------|
| | | | 1000 | 4000 |
| PBSS4032PZ | SOT223 | 8 mm pitch, 12 mm tape and reel | -115 | -135 |

[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering



12. Revision history

Table 9. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|--------------|--------------|--------------------|---------------|------------|
| PBSS4032PZ_1 | 20100331 | Product data sheet | - | - |

13. Legal information

13.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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[2] The term 'short data sheet' is explained in section "Definitions".

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15. Contents

| | | |
|-----------|--|-----------|
| 1 | Product profile | 1 |
| 1.1 | General description | 1 |
| 1.2 | Features and benefits | 1 |
| 1.3 | Applications | 1 |
| 1.4 | Quick reference data | 1 |
| 2 | Pinning information | 2 |
| 3 | Ordering information | 2 |
| 4 | Marking | 2 |
| 5 | Limiting values | 2 |
| 6 | Thermal characteristics | 4 |
| 7 | Characteristics | 6 |
| 8 | Test information | 9 |
| 8.1 | Quality information | 9 |
| 9 | Package outline | 10 |
| 10 | Packing information | 10 |
| 11 | Soldering | 11 |
| 12 | Revision history | 12 |
| 13 | Legal information | 13 |
| 13.1 | Data sheet status | 13 |
| 13.2 | Definitions | 13 |
| 13.3 | Disclaimers | 13 |
| 13.4 | Trademarks | 13 |
| 14 | Contact information | 14 |
| 15 | Contents | 15 |

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